

系所類別	科目	節次	准考證號碼 (考生請填入)	考試 日期
電機工程系碩士班（電機組）	電子學	第二節		99/5/2

※答案須寫在答案卷內，否則不予計分。

- Determine the current I_D and the diode voltage V_D for the circuit shown in Fig. 1 with $V_{DD}=5V$ and $R=2k\Omega$. Assume that the diode piecewise-linear model parameters are $V_{D0}=0.65V$ and $r_D=10\Omega$. (10%)
- For the circuit shown in Fig. 2, assume that the input signal $v_i(t)=5\sin(2\pi 50t)$ and the diode forward voltage drop $V_D=0.7V$. Plot the waveforms of $v_i(t)$ and $v_o(t)$ for $0 \leq t \leq 1/50$. (15%)

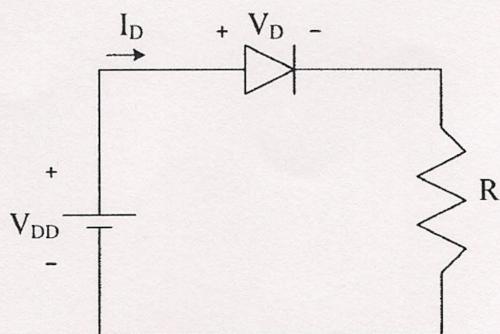


Fig. 1

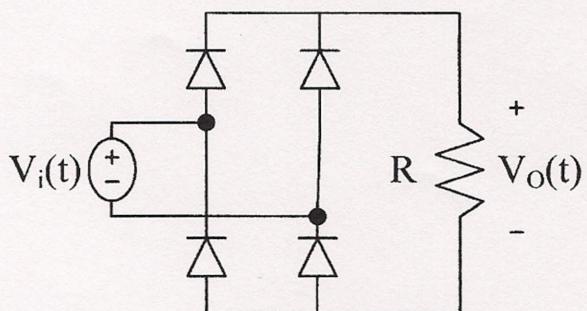


Fig. 2

- Consider the Common Emitter amplifier in Fig. 3 when the transistor is properly biased in the active region and has the following small signal parameters $\beta=100$, $g_m=40mA/V$, $r_\pi=2.5k\Omega$, and $r_o=100k\Omega$. If $R_B=100k\Omega$, $R_{sig}=5k\Omega$, $R_L=5k\Omega$, and $R_C=8k\Omega$. Find the overall voltage gain $A_v=v_o/v_{sig}$. (15%)

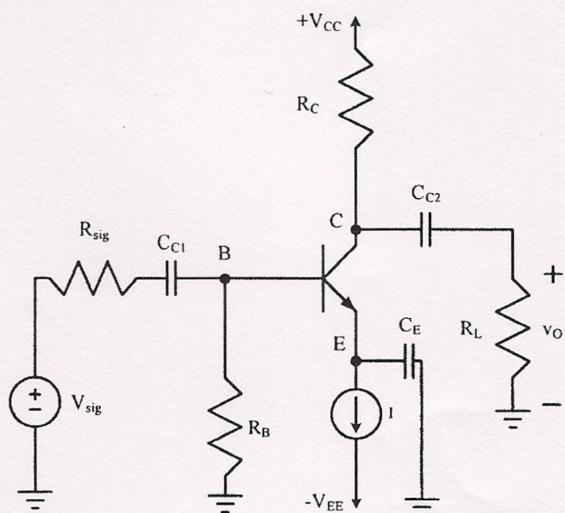


Fig. 3

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4. The Common Source amplifier shown in Fig. 4 is connected to a signal source v_{sig} with $R_{sig}=100k\Omega$ and a load resistance $R_L=15k\Omega$. Assume that the NMOSFET is properly biased in the saturation region and has the following parameters $g_m=1mA/V$ and $r_o=150k\Omega$. Find the overall voltage gain $A_v=v_o/v_{sig}$. (15%)

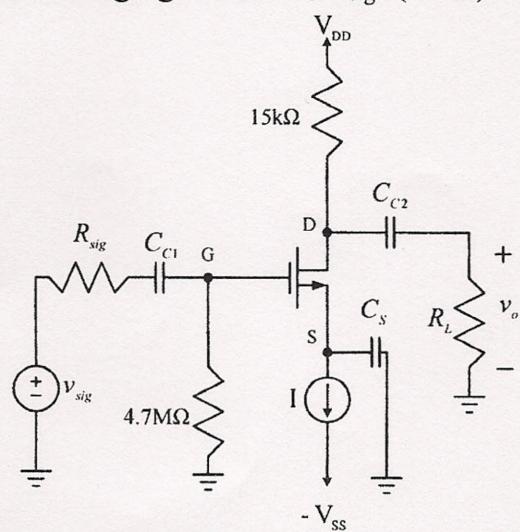


Fig. 4

5. According to the circuit shown in Fig. 5, the NMOSFET with $V_t=1.5V$ and $(\mu_n C_{ox})(W/L)=1mA/V^2$. Analyze the circuit to find V_{GS} , V_D and V_S . (15%)

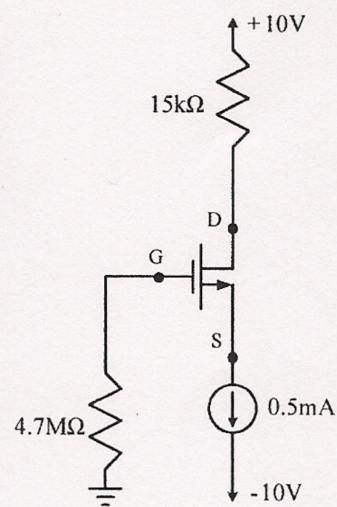


Fig. 5

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6. Consider the circuit shown in Fig. 6. Assume that the operational amplifier is ideal. Derive the voltage gain $A_v = v_o/v_i$. (15%)

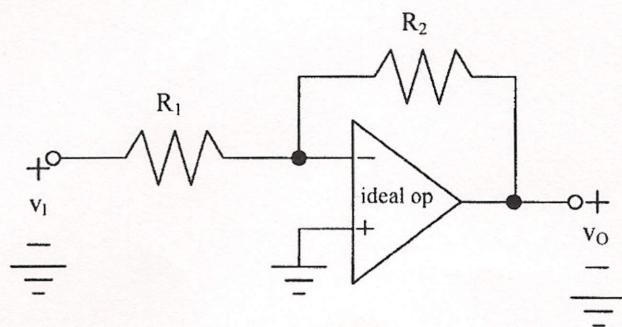


Fig. 6

7. As reference to Fig. 7, use the superposition principle to express v_o in terms of v_1 and v_2 . Assume that the operational amplifier is ideal. (15%)

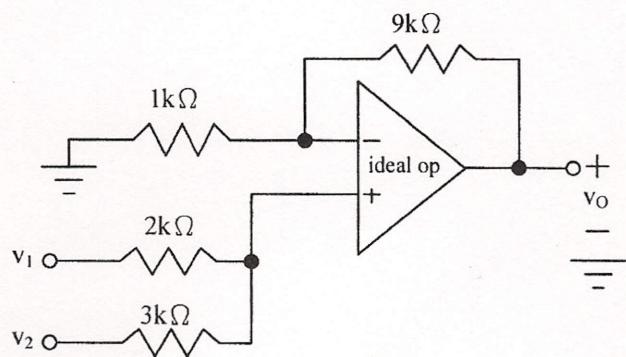


Fig. 7